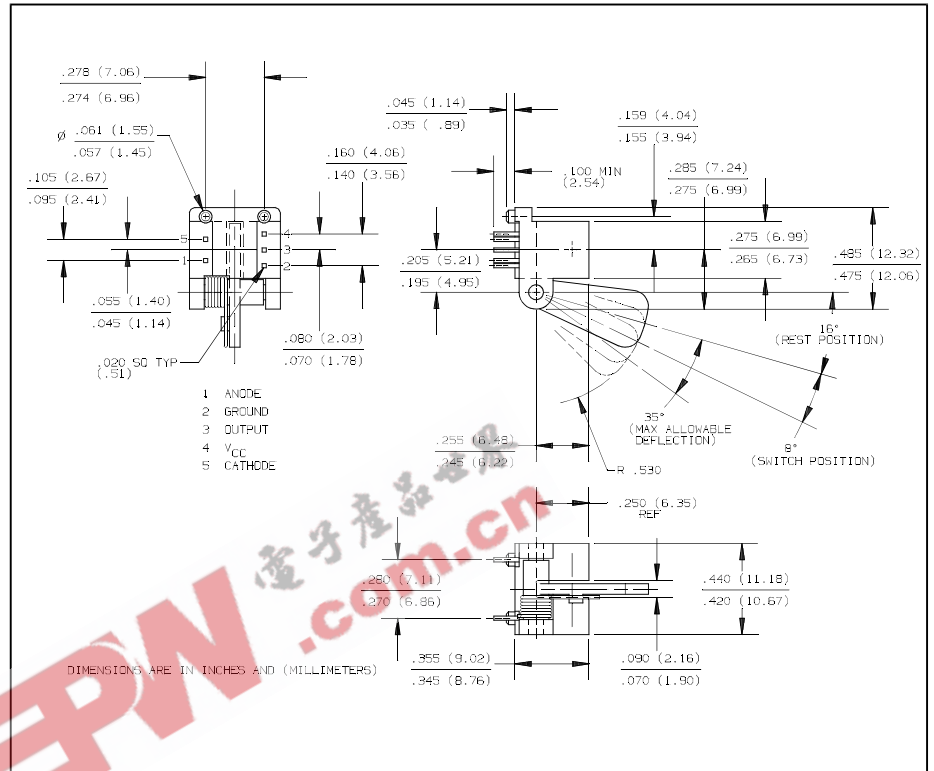
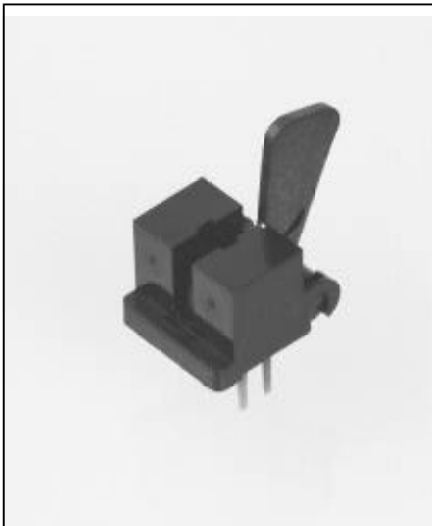


# Photologic<sup>®</sup> Optical Flag Switch

## Types OPB685, OPB686, OPB687, OPB688



### Features

- Photologic<sup>®</sup> output
- Four output options
- Mechanical switch replacement
- Printed circuit board mounting

### Description

The OPB685 series flag switches consist of an infrared emitting diode and a monolithic integrated circuit, which incorporates a photodiode, a linear amplifier and a Schmitt trigger. A lever arm actuated flag interrupts the light beam switching the output between states that can readily drive logic gates.

Customized lever arms and spring torques can be designed for specific applications.

The device features TTL/LSTTL compatible logic level output which can drive up to 10 TTL loads over a voltage range from 4.5 V to 16 V.

### Absolute Maximum Ratings (T<sub>A</sub> = 25<sup>o</sup> C unless otherwise noted)

Storage Temperature Range	-40 <sup>o</sup> C to +100 <sup>o</sup> C
Operating Temperature Range	-40 <sup>o</sup> C to +100 <sup>o</sup> C
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 sec. with soldering iron]	240 <sup>o</sup> C

### Input Diode

Forward DC Current	50 mA
Peak Forward Current (1μs pulse width, 300 pps)	3.0 A
Reverse DC Voltage	3.0 V
Power Dissipation	100 mW <sup>(2)</sup>

### Output Photologic<sup>®</sup>

Supply Voltage, V <sub>CC</sub>	18 V
Duration of Output Short To V <sub>CC</sub>	1.00 sec
Voltage at Output	30 V
Low Level Output Current (sinking)	16 mA
Power Dissipation	240 mW <sup>(3)</sup>

### Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 sec. max. when flow soldering.
- (2) Derate linearly 1.33 mW/<sup>o</sup> C above 25<sup>o</sup> C.
- (3) Derate linearly 2.50 mW/<sup>o</sup> C above 30<sup>o</sup> C.

# Types OPB685, OPB686, OPB687, OPB688

Electrical Characteristics (T<sub>A</sub> = 25° C unless otherwise noted)

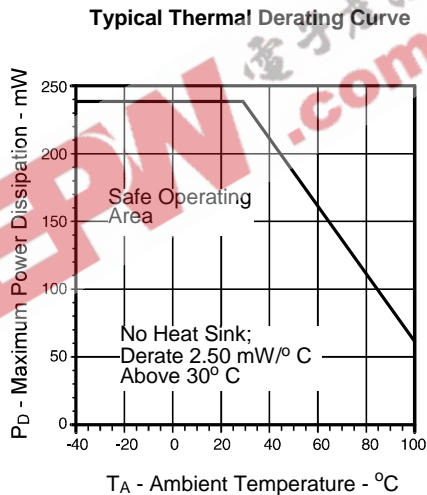
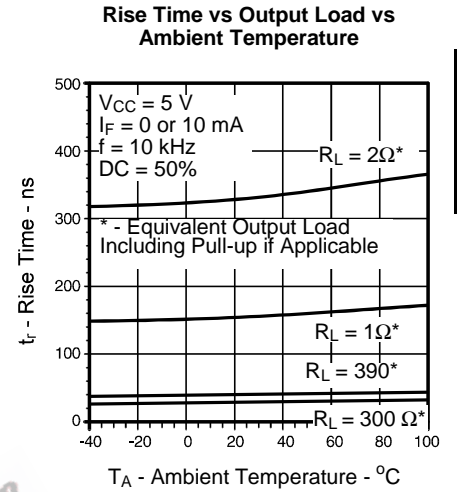
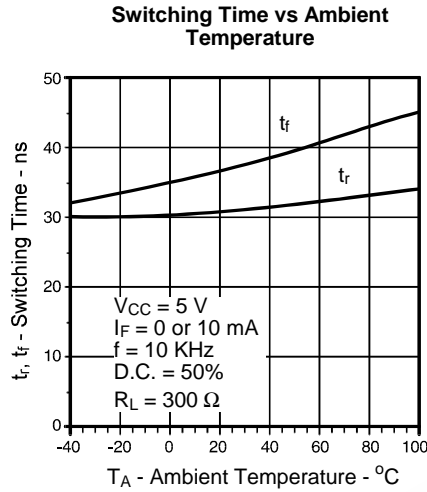
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
<b>Input Diode</b>							
V <sub>F</sub>	Forward Voltage			1.6	V	I <sub>F</sub> = 10 mA	
I <sub>R</sub>	Reverse Current			100	μA	V <sub>R</sub> = 3.0 V	
<b>Output Photologic® Sensor</b>							
V <sub>CC</sub>	Operating D.C. Supply Voltage	4.5		16.0	V		
I <sub>F</sub> (+)	LED Positive-Going Threshold Current	0.1	1.8	10.0	mA	V <sub>CC</sub> = 5.0 V	
I <sub>F</sub> (+)/I <sub>F</sub> (-)	Hysteresis Ratio	1.05	1.20	1.60		V <sub>CC</sub> = 5.0 V	
I <sub>CC</sub> H	High Level Supply Current:						
	Buffer, 10K Pull-up      OPB685 Buffer, Open-Collector    OPB686		5.0	12.0	mA	V <sub>CC</sub> = 16 V, No Load On Output, I <sub>F</sub> = 10 mA	
I <sub>CC</sub> H	Inverter, 10K Pull-up    OPB687 Inverter, Open-Collector OPB688		4.0	12.0	mA	V <sub>CC</sub> = 16 V, No Load On Output, I <sub>F</sub> = 0 mA	
	Low Level Supply Current:						
I <sub>CC</sub> L	Buffer, 10K Pull-up      OPB685 Buffer, Open-Collector    OPB686		5.5	12.0	mA	V <sub>CC</sub> = 16 V, No Load On Output, I <sub>F</sub> = 0 mA	
	Inverter, 10K Pull-up    OPB687 Inverter, Open-Collector OPB688		6.5	12.0	mA	V <sub>CC</sub> = 16 V, No Load On Output, I <sub>F</sub> = 10 mA	
V <sub>OH</sub>	High Level Output Voltage:						
	Buffer, 10K Pull-up      OPB685 Inverter, 10K Pull-up    OPB687	(V <sub>CC</sub> -1.5) <sup>(5)</sup>			V	I <sub>OH</sub> = 100 μA, I <sub>F</sub> = 10 mA	
I <sub>OH</sub>	High Level Output Current:						
	Buffer, Open-Collector    OPB686 Inverter, Open-Collector OPB688	(V <sub>CC</sub> -1.5) <sup>(5)</sup>		100	μA	V <sub>CC</sub> = 16 V, V <sub>OH</sub> = 30 V, I <sub>F</sub> = 10 mA	
V <sub>OL</sub>	Low Level Output Voltage:						
	Buffer, 10K Pull-up      OPB685 Buffer, Open-Collector    OPB686			0.4	V	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 16 mA, I <sub>F</sub> = 0 mA <sup>(4)</sup>	
V <sub>OL</sub>	Inverter, 10K Pull-up    OPB687 Inverter, Open-Collector OPB688			0.4	V	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 16 mA, I <sub>F</sub> = 10 mA	
	t <sub>r</sub> , t <sub>f</sub>	Output Rise Time, Output Fall Time		30	ns		
t <sub>PLH</sub>	Propagation Delay, Low-High						
	Buffer, 10K Pull-up      OPB685 Buffer, Open-Collector    OPB686		1.0		μs	V <sub>CC</sub> = 5 V, I <sub>F</sub> = 0 or 10 mA, f = 10 kHz, D.C. = 50%, R <sub>L</sub> = 300 Ω	
Inverter, 10K Pull-up    OPB687 Inverter, Open-Collector OPB688		2.0		μs			
t <sub>PHL</sub>	Propagation Delay, High-Low						
	Buffer, 10K Pull-up      OPB685 Buffer, Open-Collector    OPB686		2.0		μs		
t <sub>PHL</sub>	Inverter, 10K Pull-up    OPB687 Inverter, Open-Collector OPB688		1.0		μs		

(4) Normal application would be with light source blocked, simulated by I<sub>F</sub> = 0mA.

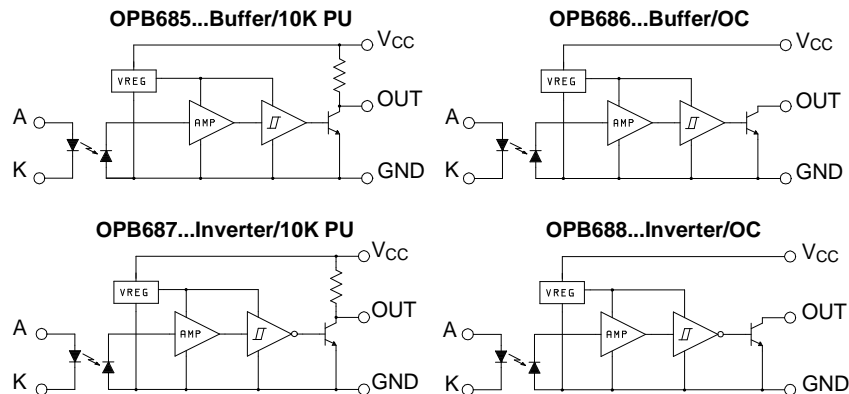
(5) V<sub>OH</sub> = V<sub>CC</sub>-1.5V for V<sub>CC</sub> = 4.5V to 16V.

# Types OPB685, OPB686, OPB687, OPB688

## Typical Performance Curves

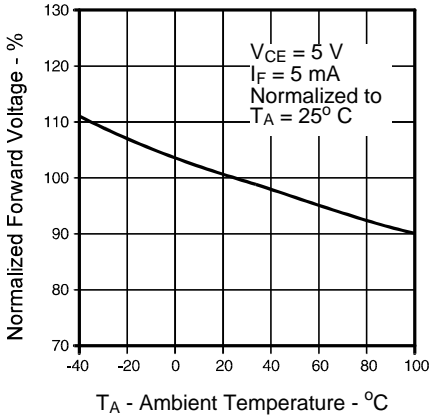


## Schematics

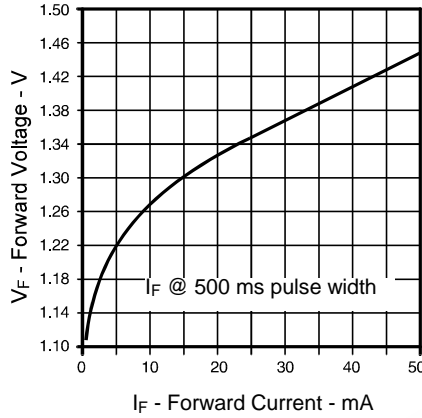


## Typical Performance Curves

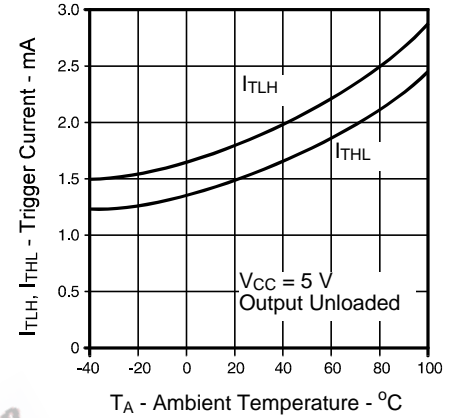
**Normalized Forward Voltage vs Ambient Temperature**



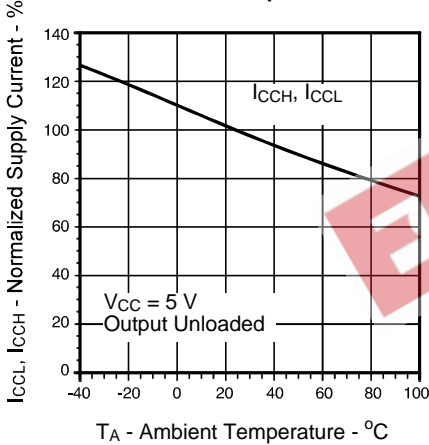
**Forward Current vs Forward Voltage Input Diode**



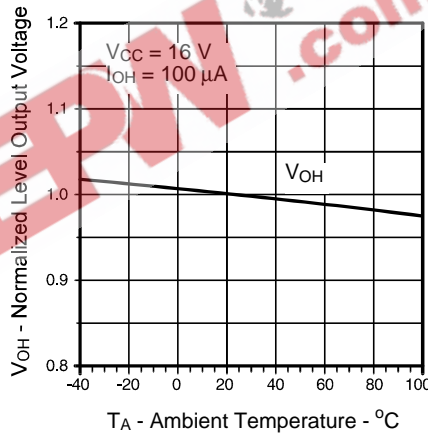
**Trigger Current vs Ambient Temperature**



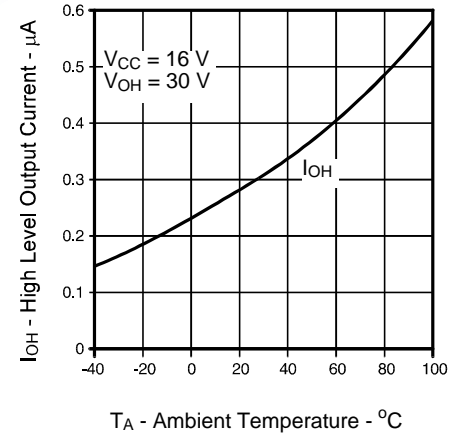
**Normalized Supply Current vs Ambient Temperature**



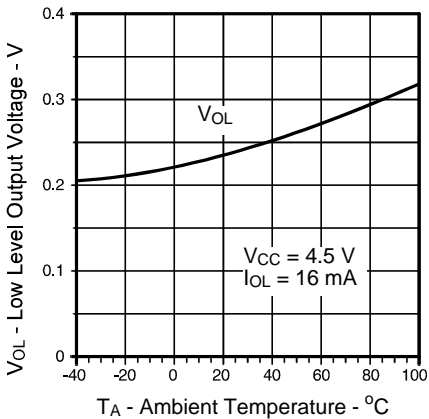
**OPB685, OPB687 Normalized High Level Output Voltage vs Ambient Temperature**



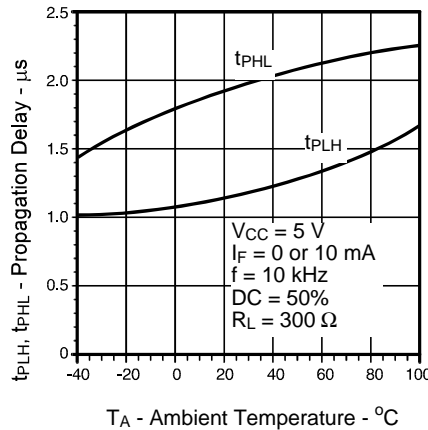
**OPB686, OPB688 High Level Output Current vs Ambient Temperature**



**Low Level Output Voltage vs Ambient Temperature**



**OPB685, OPB686 Propagation Delay vs Ambient Temperature**



**OPB687, OPB688 Propagation Delay vs Ambient Temperature**

